

BT00250-Lambda 350MHz-810MHz 250W

- Scientific and Industrial Applications



The BT-Lambda series is a range of class AB RF power amplifiers covering the 350MHz to 810MHz frequency range.

- Rugged, solid-state design - high reliability
- Extremely high phase and amplitude stability
- Very fast pulse rise/fall times
- High linearity
- Very low interpulse noise
- Competitively priced

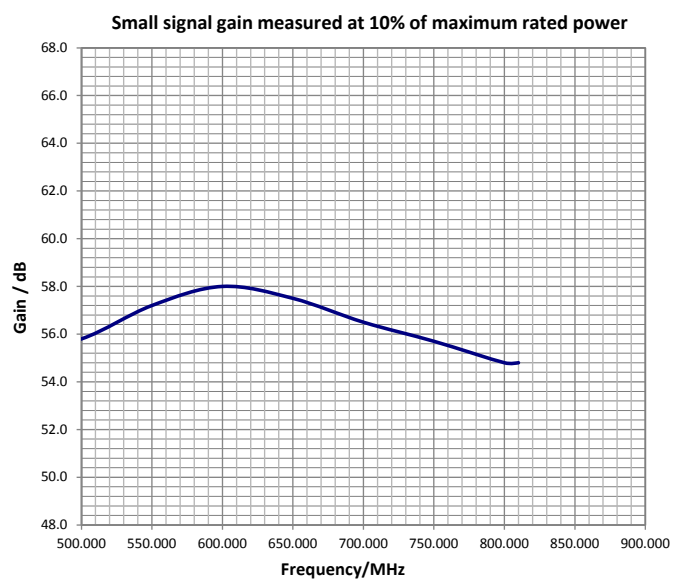
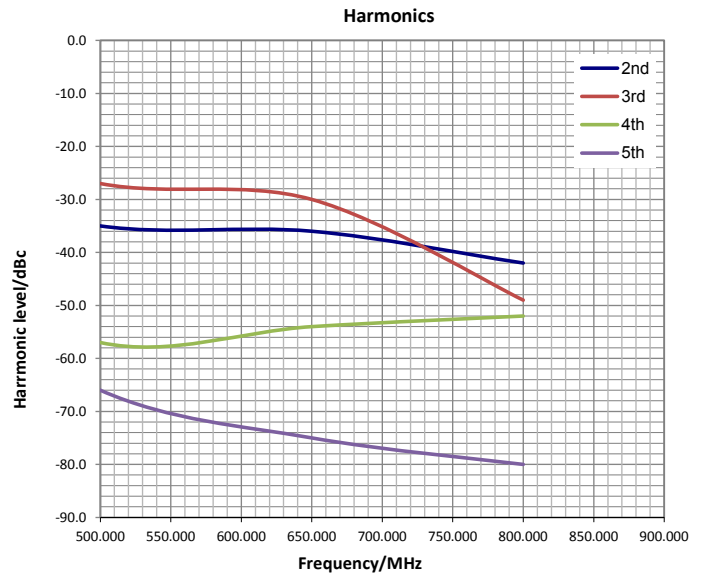
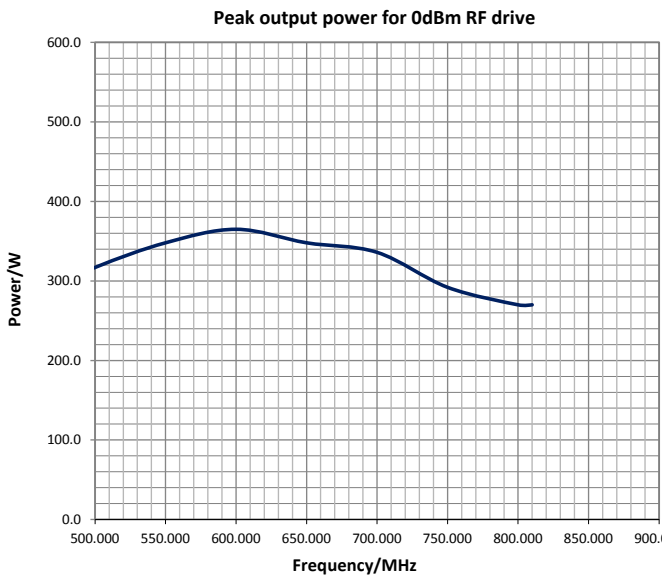
RF Specifications

Type	Class AB MOSFET
Rated Power	250W minimum PEP for input power of 0dBm
P1dB	200W minimum Minimum output power at P1dB compression
Gain	54dB minimum
Frequency	350MHz-810MHz
Gain flatness	±2dB maximum (measured at 1/10th rated output power)
Max. duty cycle	20% Maximum GATE duty cycle
Max. pulse width	300ms Maximum GATE pulse width
Rated power in CW mode	10W CW operation is automatically available at output power level less than approx. 10% of full rated power
Pulse droop	0.5dB maximum Measured at max. pulse width at P1dB level
Pulse rise and fall times	Risetime: 200ns typical Falltime: 100ns typical using a pre-gated RF input signal
Gate rise and fall times	Risetime: 300ns typical Falltime: 150ns typical
Gate delay	Rising edge: 1µs typical Falling edge: 500ns typical Rising edge measured from rising edge of GATE pulse to 90% RF output voltage. Falling edge measured from falling edge of GATE pulse to 10% RF output voltage
Harmonics	Odd: -16dBc typical, -10dBc max. Even: -30dBc typical, -20dBc max.
Spurious	<-70dBc maximum
Output noise (blanked)	<10dB above thermal (100kHz bandwidth)
Output sample	-50dB into 50 Ω (forward voltage sample)
Input/output impedance	50 Ω nominal
Load VSWR	Tolerates at least 3:1 @ full rated power without shut down
Gain control range	10dB minimum for 0-5V control voltage Control via parallel interface
RF Input	0dBm nominal, 10dBm for no damage
GATE (blanking)	Logic low = Blank, logic high = unblank. CMOS and TTL compatible

Electrical Specifications

Mains supply voltage	110-240V, 50-60Hz, single phase
Rated Power	1kVA maximum
Mains inlet	1 x IEC inlet (mains power cord supplied)

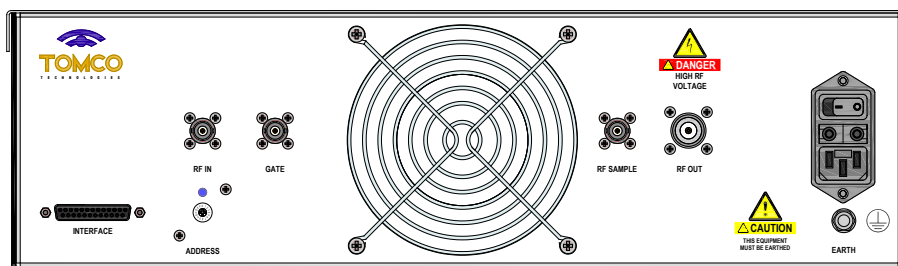
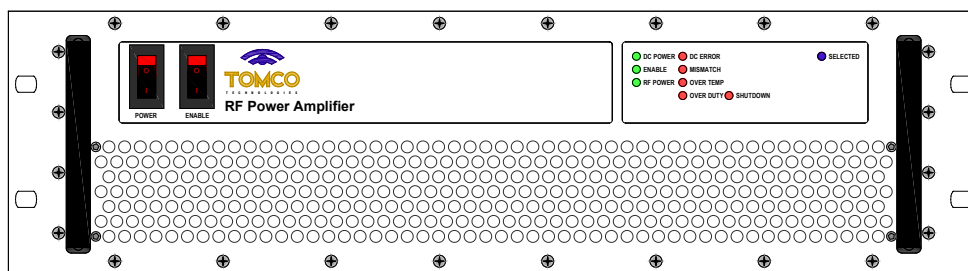
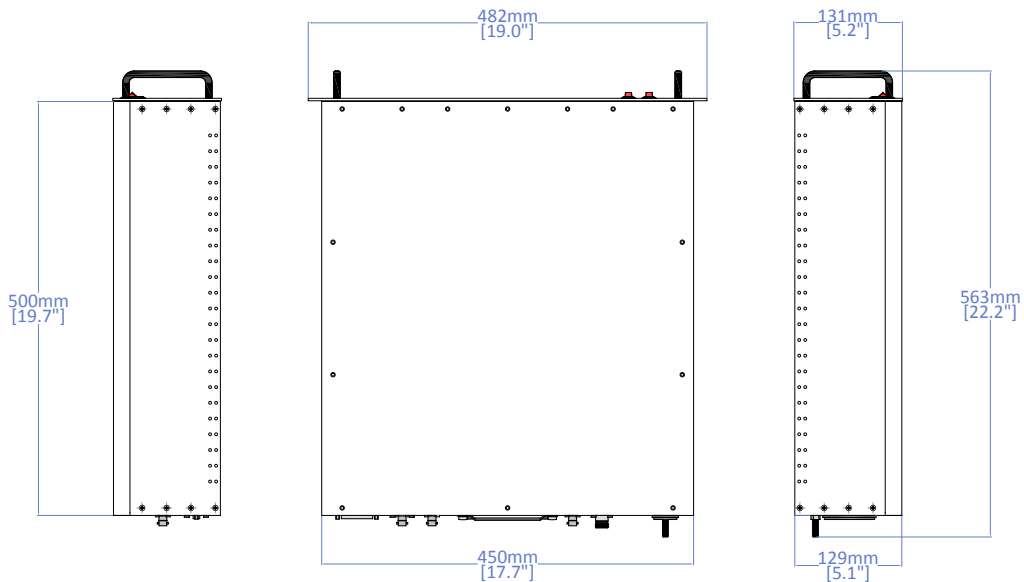
Typical Performance Plots



RF Amplifier Data Sheet

Mechanical Specifications

Connectors	RF IN: BNC female GATE: BNC female RF SAMPLE: BNC female RF OUT: N type female INTERFACE: DB25 female Other connectors types available on request
Dimensions	Chassis size: 450mmW (17.7"W) x 500mmD (19.7"D) x 129mmH (5.1"H) Total size: 482mmW (19"W) x 563mm (22.2"D) x 131mm (5.2"H) Rack compatibility: 19" 3RU
Weight	approx. 17kg (38lbs)
Enclosure classification	IP20







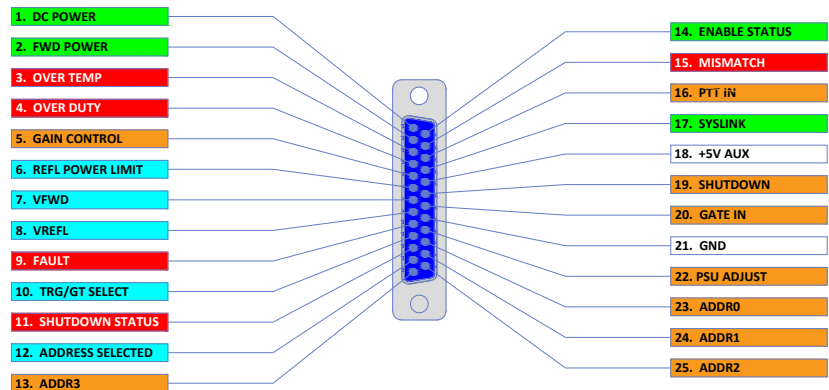
Protection

Load VSWR	Tolerates up to VSWR 3:1 at full rated power without shutdown Self-resetting shutdown protection activates if VSWR limits are exceeded
Over temperature	Self-resetting shutdown protection activates if thermal limits are exceeded
Duty cycle	Duty cycle limit is determined from the GATE signal duty cycle. Self-resetting shutdown protection activates if duty cycle limit is exceeded If output power is less than approx. 10% of maximum rated power, duty cycle protection is disabled and auto-CW operation is available
Pulse width	Pulse width limit is determined from the GATE signal pulse width. Self-resetting shutdown protection activates if pulse width limit is exceeded

Monitoring and Control

Front panel switches	Power (turns on DC power) Enable (enables RF)
Front panel LEDs	<ul style="list-style-type: none"> • DC POWER • ENABLE • RF POWER • DC ERROR • MISMATCH • OVER TEMP • OVER DUTY • SELECTED • SHUTDOWN
Parallel interface	25-pin D-connector (pinout available at www.tomcorf.com/pdf/interface.pdf)*

-  Output signal indicating normal operation
-  Output signal indicating fault condition
-  Output signal for information only
-  Input signal



*Some functions may be unavailable on select amplifier models

Environmental

General	Intended for use only in controlled, indoor environment. Non-consumer product for industrial and scientific use
Cooling	Forced air, front to rear
Operating temperature	+5°C to +40°C
Storage temperature	-20°C to +60°C
Humidity	80% for temperature up to 31°C, decreasing linearly to 50% relative humidity at 40°C
Operating altitude	Up to 2000m
Pollution degree	2
Transient voltage compatibility	Category II, in line with IEC 60364-4-44:2007
Electromagnetic compatibility	In line with IEC61326-1:2012 ISM equipment, Group 1, Class A For use only in shielded areas. ENC55011 (CISPR 11) limits exceeded by up to 40dB
Safety	In line with IEC61010-1:2010
Electromagnetic field strength	In line with ICNIRP Guidelines: 1998, occupational limits

Change record

Document/Issue number	Originator	Date	Change
DS006691A	JR	31/07/18	Original